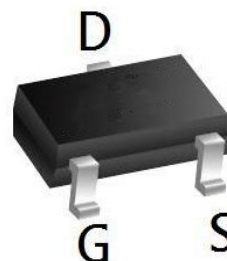


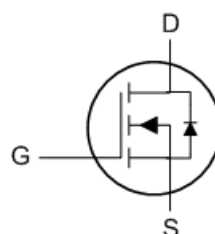
## Product Summary

| BVDSS | RDSON | ID  |
|-------|-------|-----|
| 40V   | 30mΩ  | 5 A |

- ★ Green Device Available
- ★ Super Low Gate Charge
- ★ Excellent CdV/dt effect decline
- ★ Advanced high cell density Trench technology



**SOT-23**



## Absolute Maximum Ratings ( $T_A=25^{\circ}\text{C}$ unless otherwise specified)

| Symbol          | Parameter                               |                             | Max.        | Units                |
|-----------------|-----------------------------------------|-----------------------------|-------------|----------------------|
| $V_{DSS}$       | Drain-Source Voltage                    |                             | 40          | V                    |
| $V_{GSS}$       | Gate-Source Voltage                     |                             | $\pm 20$    | V                    |
| $I_D$           | Continuous Drain Current                | $T_A = 25^{\circ}\text{C}$  | 5           | A                    |
|                 |                                         | $T_A = 100^{\circ}\text{C}$ | 3           | A                    |
| $I_{DM}$        | Pulsed Drain Current <sup>note1</sup>   |                             | 20          | A                    |
| $P_D$           | Power Dissipation                       | $T_A = 25^{\circ}\text{C}$  | 1.6         | W                    |
| $R_{\theta JA}$ | Thermal Resistance, Junction to Ambient |                             | 78          | $^{\circ}\text{C/W}$ |
| $T_J, T_{STG}$  | Operating and Storage Temperature Range |                             | -55 to +150 | $^{\circ}\text{C}$   |

**Electrical Characteristics** ( $T_J=25^{\circ}\text{C}$  unless otherwise specified)

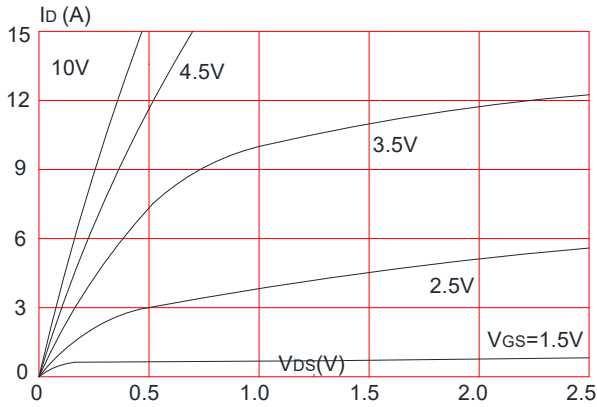
| Symbol                                                 | Parameter                                                 | Test Condition                                                                                                 | Min. | Typ. | Max. | Units |
|--------------------------------------------------------|-----------------------------------------------------------|----------------------------------------------------------------------------------------------------------------|------|------|------|-------|
| Off Characteristic                                     |                                                           |                                                                                                                |      |      |      |       |
| V <sub>(BR)DSS</sub>                                   | Drain-Source Breakdown Voltage                            | V <sub>GS</sub> =0V, I <sub>D</sub> =250μA                                                                     | 40   | -    | -    | V     |
| I <sub>DSS</sub>                                       | Zero Gate Voltage Drain Current                           | V <sub>DS</sub> =40V, V <sub>GS</sub> =0V,                                                                     | -    | -    | 1.0  | μA    |
| I <sub>GSS</sub>                                       | Gate to Body Leakage Current                              | V <sub>DS</sub> =0V, V <sub>GS</sub> = ±20V                                                                    | -    | -    | ±100 | nA    |
| On Characteristics                                     |                                                           |                                                                                                                |      |      |      |       |
| V <sub>GS(th)</sub>                                    | Gate Threshold Voltage                                    | V <sub>DS</sub> =V <sub>GS</sub> , I <sub>D</sub> =250μA                                                       | 1.0  | 1.5  | 2.2  | V     |
| R <sub>DS(on)</sub>                                    | Static Drain-Source on-Resistance<br><small>note3</small> | V <sub>GS</sub> =10V, I <sub>D</sub> =4A                                                                       | -    | 30   | 40   | mΩ    |
|                                                        |                                                           | V <sub>GS</sub> =4.5V, I <sub>D</sub> =3A                                                                      | -    | 40   | 60   |       |
| Dynamic Characteristics                                |                                                           |                                                                                                                |      |      |      |       |
| C <sub>iss</sub>                                       | Input Capacitance                                         | V <sub>DS</sub> =20V, V <sub>GS</sub> =0V,<br>f=1.0MHz                                                         | -    | 435  | -    | pF    |
| C <sub>oss</sub>                                       | Output Capacitance                                        |                                                                                                                | -    | 58   | -    | pF    |
| C <sub>rss</sub>                                       | Reverse Transfer Capacitance                              |                                                                                                                | -    | 35   | -    | pF    |
| Q <sub>g</sub>                                         | Total Gate Charge                                         | V <sub>DS</sub> =20V, I <sub>D</sub> =3A,<br>V <sub>GS</sub> =10V                                              | -    | 11   | -    | nC    |
| Q <sub>gs</sub>                                        | Gate-Source Charge                                        |                                                                                                                | -    | 2    | -    | nC    |
| Q <sub>gd</sub>                                        | Gate-Drain(“Miller”) Charge                               |                                                                                                                | -    | 2.5  | -    | nC    |
| Switching Characteristics                              |                                                           |                                                                                                                |      |      |      |       |
| t <sub>d(on)</sub>                                     | Turn-on Delay Time                                        | V <sub>DD</sub> =20V, I <sub>D</sub> =4A,<br>R <sub>L</sub> =1Ω, R <sub>GEN</sub> =3Ω,<br>V <sub>GS</sub> =10V | -    | 10   | -    | ns    |
| t <sub>r</sub>                                         | Turn-on Rise Time                                         |                                                                                                                | -    | 8    | -    | ns    |
| t <sub>d(off)</sub>                                    | Turn-off Delay Time                                       |                                                                                                                | -    | 29   | -    | ns    |
| t <sub>f</sub>                                         | Turn-off Fall Time                                        |                                                                                                                | -    | 12   | -    | ns    |
| Drain-Source Diode Characteristics and Maximum Ratings |                                                           |                                                                                                                |      |      |      |       |
| I <sub>S</sub>                                         | Maximum Continuous Drain to Source Diode Forward Current  |                                                                                                                | -    | -    | 5    | A     |
| I <sub>SM</sub>                                        | Maximum Pulsed Drain to Source Diode Forward Current      |                                                                                                                | -    | -    | 20   | A     |
| V <sub>SD</sub>                                        | Drain to Source Diode Forward Voltage                     | V <sub>GS</sub> =0V, I <sub>S</sub> =5A                                                                        | -    | -    | 1.2  | V     |
| t <sub>rr</sub>                                        | Body Diode Reverse Recovery Time                          | T <sub>J</sub> =25℃,<br>I <sub>F</sub> =5A,dI/dt=100A/μs                                                       | -    | 20   | -    | ns    |
| Q <sub>rr</sub>                                        | Body Diode Reverse Recovery Charge                        |                                                                                                                | -    | 11   | -    | nC    |

Notes:1. Repetitive Rating: Pulse Width Limited by Maximum Junction Temperature

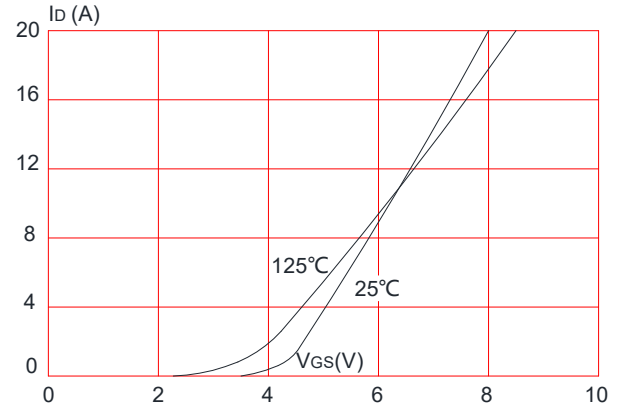
2. Pulse Test: Pulse Width $\leq 300\mu s$ , Duty Cycle $\leq 0.5\%$

## Typical Performance Characteristics

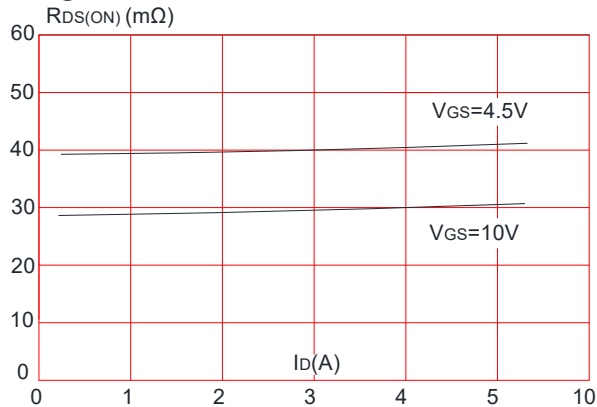
**Figure 1: Output Characteristics**



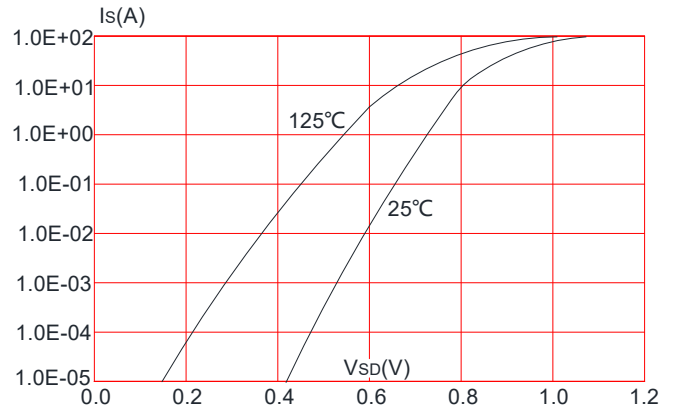
**Figure 2: Typical Transfer Characteristics**



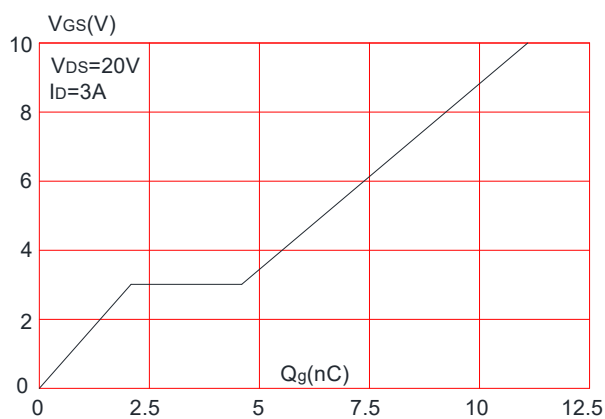
**Figure 3: On-resistance vs. Drain Current**



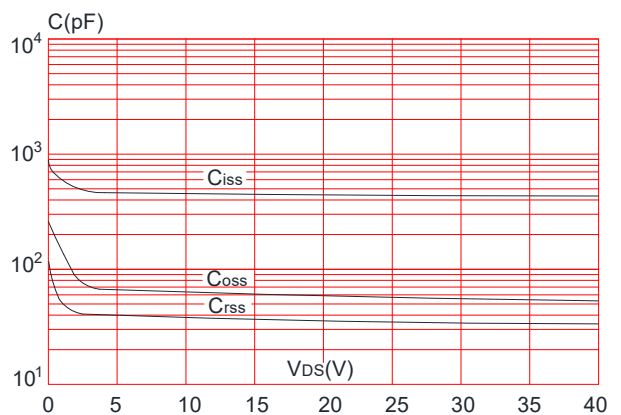
**Figure 4: Body Diode Characteristics**



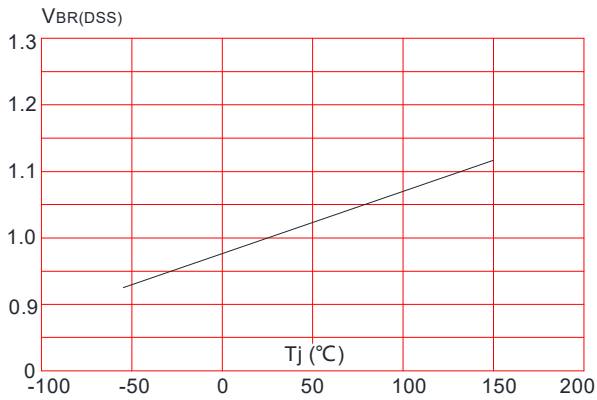
**Figure 5: Gate Charge Characteristics**



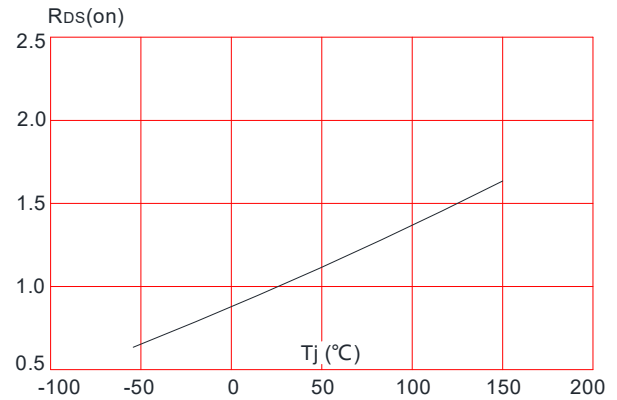
**Figure 6: Capacitance Characteristics**



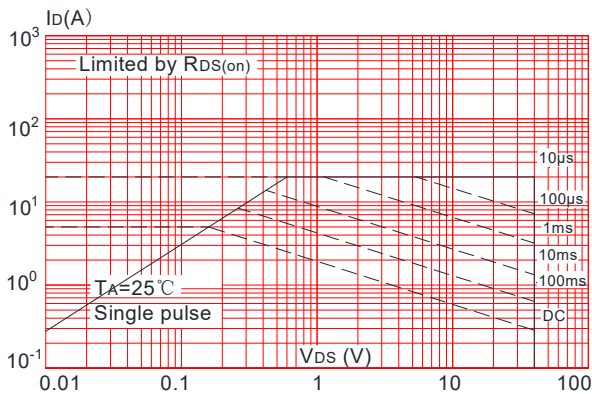
**Figure 7:** Normalized Breakdown Voltage vs. Junction Temperature



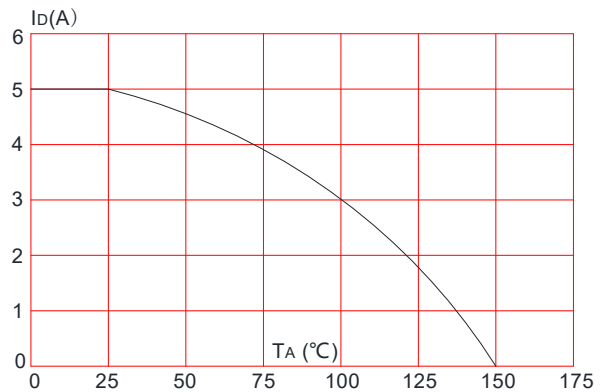
**Figure 8:** Normalized on Resistance vs. Junction Temperature



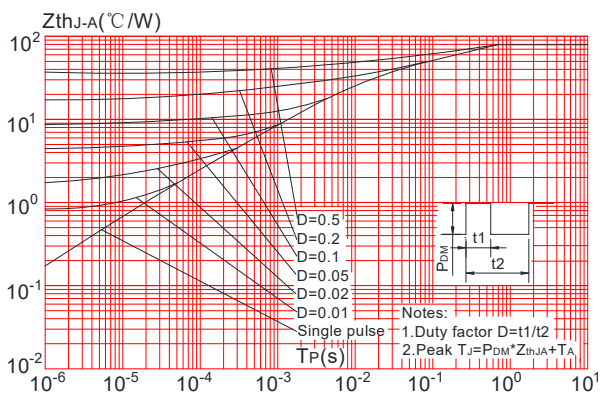
**Figure 9:** Maximum Safe Operating Area



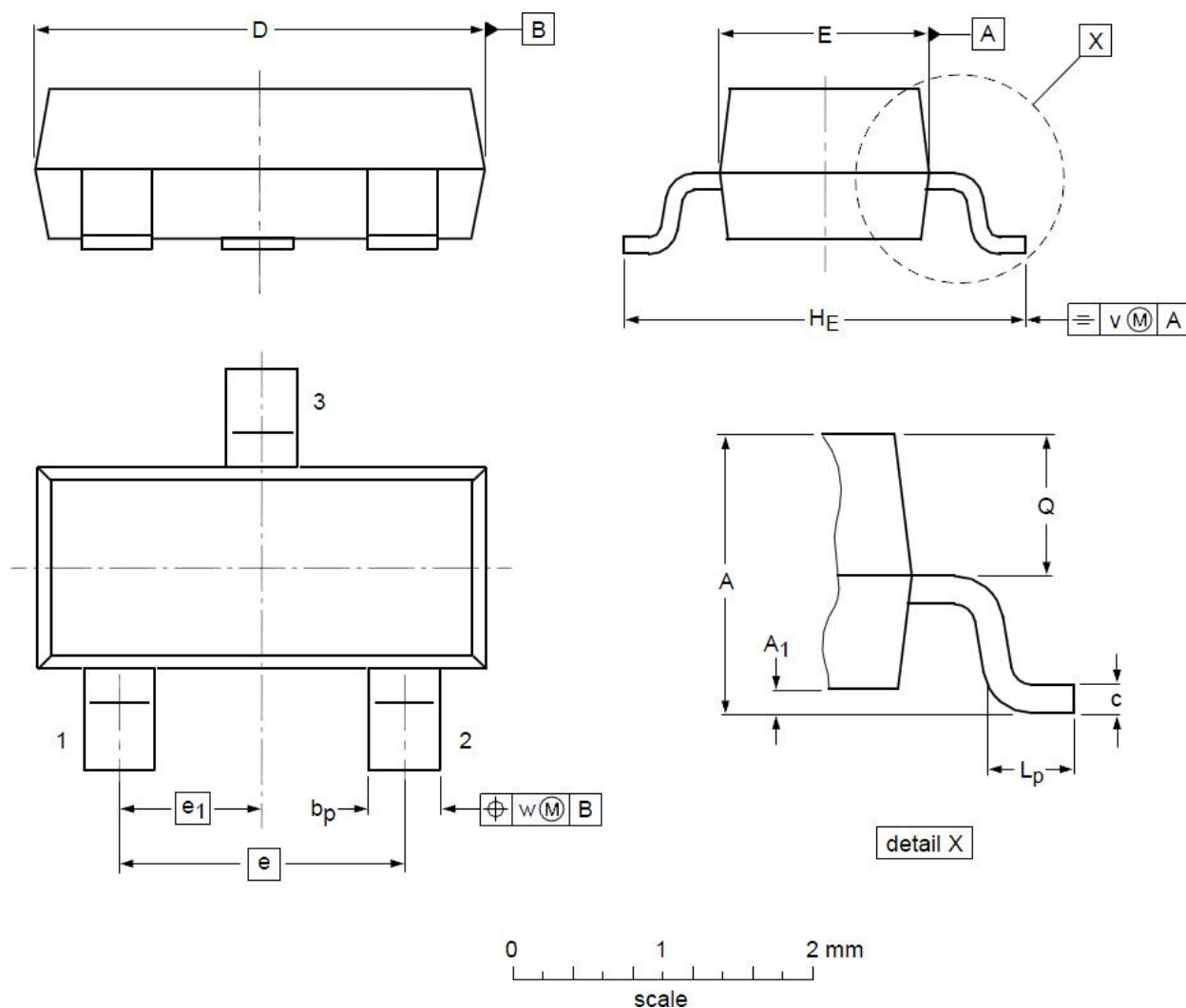
**Figure 10:** Maximum Continuous Drain Current vs. Ambient Temperature



**Figure.11:** Maximum Effective Transient Thermal Impedance, Junction-to-Ambient



**SOT23 Mechanical Data**



**DIMENSIONS ( unit : mm )**

| Symbol               | Min  | Typ  | Max  | Symbol               | Min  | Typ  | Max  |
|----------------------|------|------|------|----------------------|------|------|------|
| <b>A</b>             | 0.90 | 1.01 | 1.15 | <b>A<sub>1</sub></b> | 0.01 | 0.05 | 0.10 |
| <b>b<sub>p</sub></b> | 0.30 | 0.42 | 0.50 | <b>c</b>             | 0.08 | 0.13 | 0.15 |
| <b>D</b>             | 2.80 | 2.92 | 3.00 | <b>E</b>             | 1.20 | 1.33 | 1.40 |
| <b>e</b>             | --   | 1.90 | --   | <b>e<sub>1</sub></b> | --   | 0.95 | --   |
| <b>H<sub>E</sub></b> | 2.25 | 2.40 | 2.55 | <b>L<sub>p</sub></b> | 0.30 | 0.42 | 0.50 |
| <b>Q</b>             | 0.45 | 0.49 | 0.55 | <b>v</b>             | --   | 0.20 | --   |
| <b>w</b>             | --   | 0.10 | --   |                      |      |      |      |